# MSKSEMI















**ESD** 

TVS

**TSS** 

MOV

**GDT** 

**PLED** 

Brodnet data speet

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#### **FEATURES**

- · Low forward voltage
- · High current capability
- · High forward surge capability
- Low power losses, High efficiency
- Guarding for over voltage protection

#### **APPLICATIONS**

Low VF Schottky barrier rectifier are designed for high frequency, miniature switched mode power supplies such as adapters ,lighting and on-board DC/DC conerters

Primary Characteristic		
lo	2*5A	
$V_{RRM}$	100V	
I <sub>FSM</sub>	120A	
V <sub>F</sub>	0.65V	
T₃max	150℃	
Assembly code	Al	

### **MECHANICAL DATA**

Case: Molded plasticPolarity: As markedMounting Position: Any

• Molded Plastic: UL Flammability Classification Rating 94V-0
• Lead free in compliance with EU RoHS 2011/65/EU directive

• Solder bath temperature 275°C maximum,10s per JESD22-B106

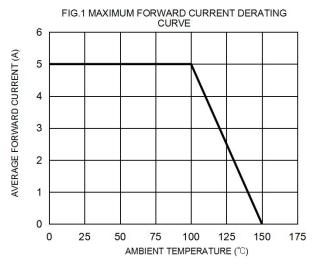
Maximum Ratings (Per Leg) at Ta=25°C unless otherwise specified				
Characteristics		Symbol	Value	Unit
Maximum Repetitive Peak Reverse Voltage		V <sub>RRM</sub>	100	V
Working Peak Reverse Voltage		V <sub>RWM</sub>	100	V
Maximum DC Blocking Voltage		V <sub>DC</sub>	100	V
Maximum Average Forward Rectified Current	Per Leg		5	۸
	Total		10	A
Peak Forward Surge Current, 8.3 ms Single Ha	If Sine-wave	I <sub>FSM</sub>	120	А
Operating Temperature Range		TJ	150	°C
Storage Temperature Range		T <sub>STG</sub>	-40 to +150	°C
Typical Thermal Resistance (Note1)				
TO-220AB,TO-263,TO-252		R <sub>e IC</sub>	2	°C/W
TO-220F			4	

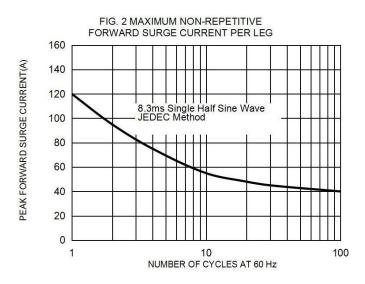
Note1: Thermal resistance from Junction to case per leg mounted on heatsink.

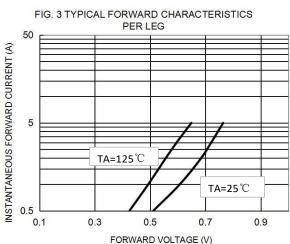
Electrical Characteristics (Pe	er Leg) unles	s otherwi	se specified		
Characteristics		Symbol	Val	ue	Unit
Forward Voltage Drop(Note2)			Тур.	Max.	
	TA=25°C		0.68	-	
at I <sub>F</sub> =2A	TA=125°C		0.56	-	
-A.I2.A	TA=25°C	$V_{F}$	0.72	-	V
at I <sub>F</sub> =3A	TA=125°C		0.60	-	
at I <sub>F</sub> =5A	TA=25°C	]	0.76	0.85	
	TA=125°C		0.65	-	
Maximum Reverse Current at V <sub>R</sub> =100V	TA=25°C		0.001	0.1	mA
	TA=125°C	I <sub>R</sub>	0.6	-	mA

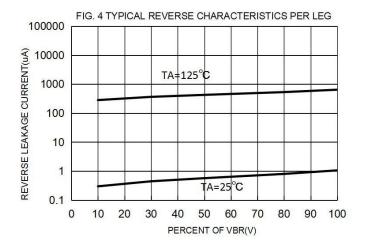
Note2:Pulse test: 300 µs pulse width, 1 % duty cycle

#### RATINGS AND CHARACTERISTIC CURVES

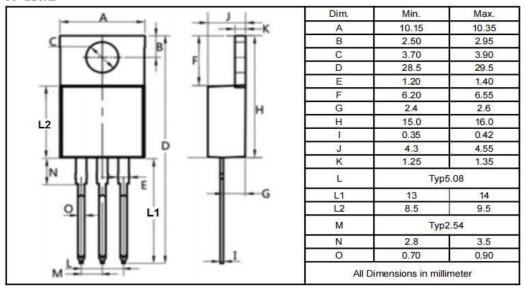








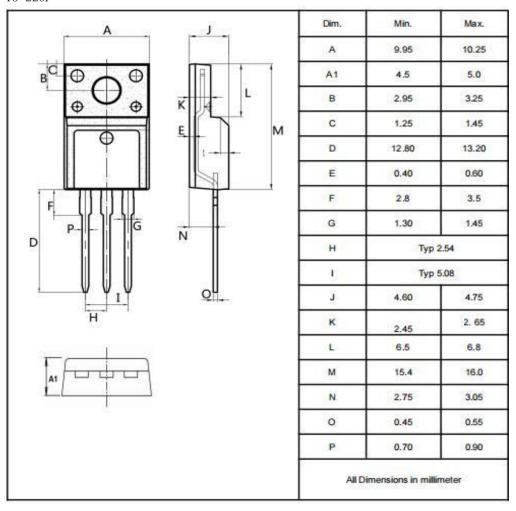
TO-220AB



P/N	PKG	QTY
MBR10100CT-MS	TO-220AB	50pcs/tube 1000pcs/box

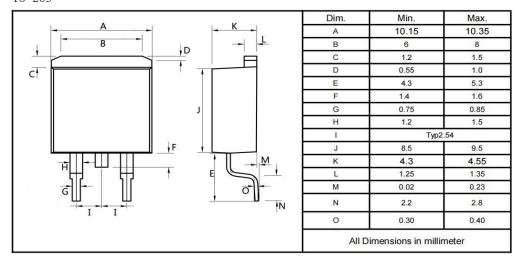


TO-220F



P/N	PKG	QTY
MBR10100FCT-MS	TO-220F	50pcs/tube 1000pcs/box

TO-263

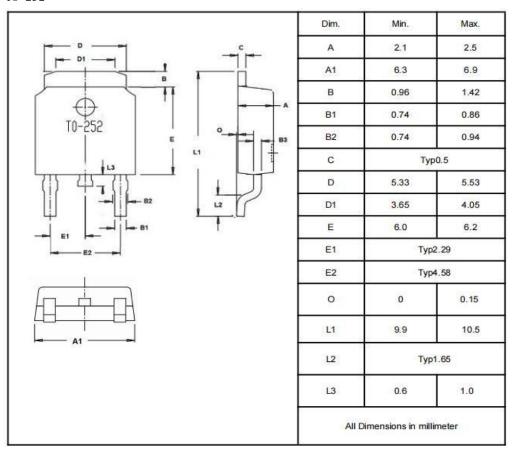


#### **REEL SPECIFICATION**

P/N	PKG	QTY
MBR10100DC-MS	TO-263	50pcs/tube 1000pcs/box

P/N	PKG	QTY
MBR10100DC-R-MS	TO-263	800pcs

TO-252



P/N	PKG	QTY
MBR10100CS-MS	TO-252	2500



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